<u>\$MF05C, \$MF</u>12C, \$MF15C, SMF24C

5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-88 package.

- Protects up to 5-Line in a Single SC-88 Package
- Peak Power Dissipation 100 W (8 x 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8 kV (Contact)
- Flammability Rating of UL 94 V-0
- Pb-Free Packages are Available

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T, =25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation 8 x 20 μs Double Exponential Waveform	100	W
	(Note 1)		
T_J	Operating Junction Temperature Range	-40 to 125	°C
T _{STG}	Storage Temperature Range	–55 to 150	°C
T_L	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 15000	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1

1. Nonrepetitive current pulse per Figure 3.



ON Semiconductor®

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SC-88 FIVE TRANSIENT VOLTAGE SUPPRESSOR 100 W PEAK POWER

MARKING DIAGRAM



SC-88 **CASE 419B** STYLE 24



XX = Specific Device Code

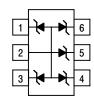
> 6J = SMF05C6K = SMF12C

6L = SMF15C 6M = SMF24C

= Date Code

= Pb-Free Package

PIN ASSIGNMENT



PIN1. CATHODE

- 2. ANODE
- 3 CATHODE
- 4. CATHODE
- 5. CATHODE
- 6. CATHODE

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

ENGOSO / FLOST RICALLICITARIACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Reverse Working Voltage	V_{RWM}	(Note 2)			5.0	V	
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	T = 1 mA, (Note 3) 6.2		7.2	V	
Reverse Leakage Current	I _R	V _{RWM} = 5 V		0.07	5.0	μΑ	
Clamping Voltage	V _C	I _{PP} = 5 A (8 x 20 μs Waveform)			9.8	V	
Clamping Voltage	V _C	I _{PP} = 8 A (8 x 20 μs Waveform)			12.5	V	
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			8.0	Α	
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		80	130	pF	

SMF12C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			12	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)			15	V
Reverse Leakage Current	I _R	V _{RWM} = 12 V		0.01	0.1	μΑ
Clamping Voltage	V _C	I _{PP} = 3 A (8 x 20 μs Waveform)			21	V
Clamping Voltage	V _C	I _{PP} = 6 A (8 x 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			6.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		40	60	pF

SMF15C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

Parameter	Symbol Conditions		Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			15	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, (Note 3)	17		19	V
Reverse Leakage Current	I _R V _{RWM} = 15 V			0.01	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 1 A (8 x 20 μs Waveform)			23	V
Clamping Voltage V_C $I_{PP} = 5 \text{ A } (8 \text{ x } 20 \mu \text{s } \text{Wave})$		I _{PP} = 5 A (8 x 20 μs Waveform)			29	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			5.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		33	45	pF

SMF24C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			24	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	26.7		32	V
Reverse Leakage Current	I _R	V _{RWM} = 24 V		0.01	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 1 A (8 x 20 μs Waveform)			40	V
Clamping Voltage	V _C	I _{PP} = 2.5 A (8 x 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			2.5	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		21	25	pF

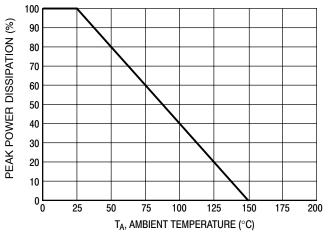
^{2.} TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V_{BR} is measured at pulse test current I_T.

查询"SMF05C_05"供应商

TYPICAL PERFORMANCE CURVES

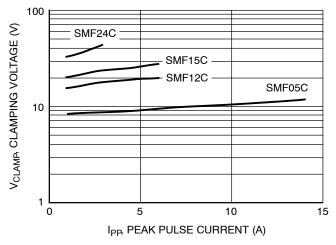
(T_J = 25°C unless otherwise specified)



100 PEAK VALUE $I_{RSM} \ @ \ 8 \ \mu s$ 90 OF PEAK PULSE CURRENT PULSE WIDTH (tp) IS DEFINED 80 AS THAT POINT WHERE THE 70 PEAK CURRENT DECAY = 8 μs 60 HALF VALUE I_{RSM}/2 @ 20 μs 50 40 30 20 10 0 20 40 60 80 0 t, TIME (μs)

Figure 1. Pulse Derating Curve

Figure 2. $8 \times 20 \mu s$ Pulse Waveform



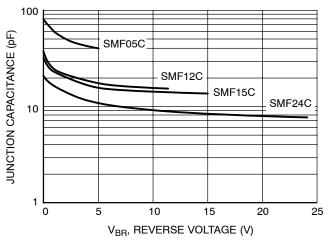


Figure 3. Clamping Voltage vs Peak Pulse Current

Figure 4. Junction Capacitance vs Reverse Voltage

查用DERING INFORMATION商

Device	Package	Shipping [†]
SMF05CT1	SC-88	3000 / Tape & Reel
SMF05CT1G	SC-88 (Pb-Free)	3000 / Tape & Reel
SMF05CT2*	SC-88	3000 / Tape & Reel
SMF05CT2G*	SC-88 (Pb-Free)	3000 / Tape & Reel
SMF12CT1	SC-88	3000 / Tape & Reel
SMF12CT1G	SC-88 (Pb-Free)	3000 / Tape & Reel
SMF15CT1	SC-88	3000 / Tape & Reel
SMF15CT1G	SC-88 (Pb-Free)	3000 / Tape & Reel
SMF24CT1	SC-88	3000 / Tape & Reel
SMF24CT1G	SC-88 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*The "T2" suffix refers to an alternate tape & reel orientation.

查询"SMF05C_05"供应商

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE V

 H_{E} **b** 6 PL 0.2 (0.008) M E M

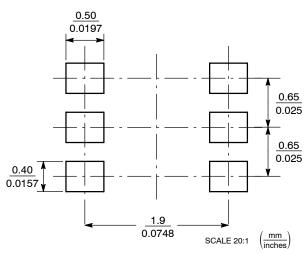
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
А3		0.20 RE	F		0.008 RI	EF.
b	0.10	0.21	0.30	0.004	0.008	0.012
С	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
е	(0.65 BS	С	0	.026 BS	С
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086

- STYLE 24:
 PIN 1. CATHODE
 2. ANODE
 3. CATHODE
 4. CATHODE
 5. CATHODE
 6. CATHODE

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

查询"SMF05C_05"供应商

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